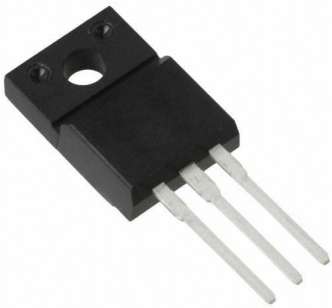


# 2SA21400P Datasheet

[www.digi-electronics.com](http://www.digi-electronics.com)



<https://www.DiGi-Electronics.com>

DiGi Electronics Part Number	2SA21400P-DG
Manufacturer	<a href="#">Panasonic Electronic Components</a>
Manufacturer Product Number	2SA21400P
Description	TRANS PNP 180V 1.5A TO220D-A1
Detailed Description	Bipolar (BJT) Transistor PNP 180 V 1.5 A 100MHz 2 W Through Hole TO-220D-A1



Tel: +00 852-30501935

RFQ Email: [Info@DiGi-Electronics.com](mailto:Info@DiGi-Electronics.com)

DiGi is a global authorized distributor of electronic components.

## Purchase and inquiry

Manufacturer Product Number:

2SA21400P

Series:

-

Transistor Type:

PNP

Voltage - Collector Emitter Breakdown (Max):

180 V

Current - Collector Cutoff (Max):

100 $\mu$ A (ICBO)

Power - Max:

2 W

Operating Temperature:

150°C (TJ)

Package / Case:

TO-220-3 Full Pack

Base Product Number:

2SA214

Manufacturer:

Panasonic Electronic Components

Product Status:

Obsolete

Current - Collector (Ic) (Max):

1.5 A

Vce Saturation (Max) @ Ib, Ic:

500mV @ 100mA, 1A

DC Current Gain (hFE) (Min) @ Ic, Vce:

120 @ 100mA, 5V

Frequency - Transition:

100MHz

Mounting Type:

Through Hole

Supplier Device Package:

TO-220D-A1

## Environmental & Export classification

Moisture Sensitivity Level (MSL):

1 (Unlimited)

HTSUS:

8541.29.0075

ECCN:

EAR99

# 2SA2140

## Silicon PNP epitaxial planar type

For power amplification

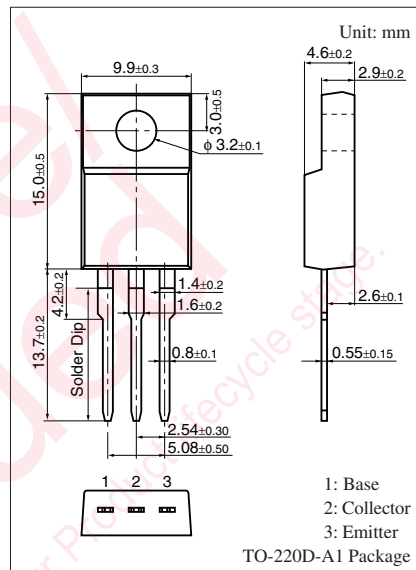
For TV VM circuit

### ■ Features

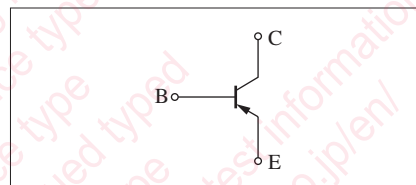
- Satisfactory linearity of forward current transfer ratio  $h_{FE}$
- High transition frequency ( $f_T$ )
- Full-pack package which can be installed to the heat sink with one screw.

### ■ Absolute Maximum Ratings $T_C = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	$V_{CBO}$	-180	V
Collector-emitter voltage (Base open)	$V_{CEO}$	-180	V
Emitter-base voltage (Collector open)	$V_{EBO}$	-6	V
Collector current	$I_C$	-1.5	A
Peak collector current	$I_{CP}$	-3	A
Collector power dissipation	$P_C$	20	W
	$T_a = 25^\circ\text{C}$	2.0	
Junction temperature	$T_j$	150	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-55 to +150	$^\circ\text{C}$



### Internal Connection



### ■ Electrical Characteristics $T_C = 25^\circ\text{C} \pm 3^\circ\text{C}$

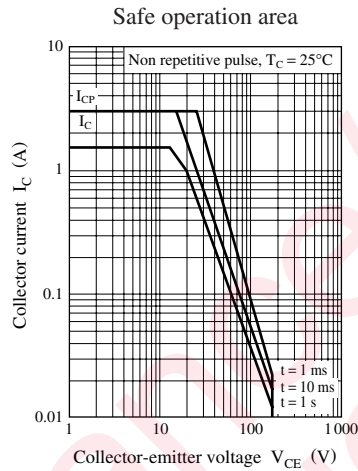
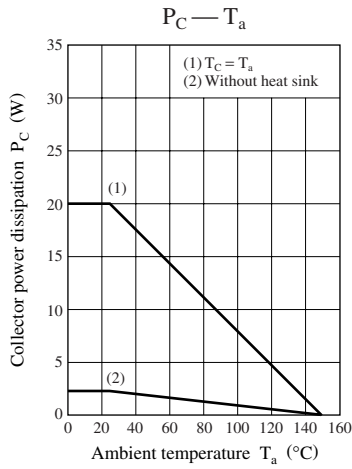
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-emitter voltage (Base open)	$V_{CEO}$	$I_C = -10 \text{ mA}, I_B = 0$	-180			V
Collector-base cutoff current (Emitter open)	$I_{CBO}$	$V_{CB} = -180 \text{ V}, I_E = 0$			-100	$\mu\text{A}$
Emitter-base cutoff current (Collector open)	$I_{EBO}$	$V_{EB} = -6 \text{ V}, I_C = 0$			-100	$\mu\text{A}$
Forward current transfer ratio *	$h_{FE}$	$V_{CE} = -5 \text{ V}, I_C = -0.1 \text{ A}$	60		240	—
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -1 \text{ A}, I_B = -0.1 \text{ A}$			-0.5	V
Transition frequency	$f_T$	$V_{CE} = -10 \text{ V}, I_C = -0.2 \text{ A}, f = 10 \text{ MHz}$		100		MHz
Collector output capacitance (Common base, input open circuited)	$C_{ob}$	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		30		pF
Turn-on time	$t_{on}$	$I_C = -0.4 \text{ A}, \text{Resistance loaded}$		0.1		$\mu\text{s}$
Storage time	$t_{stg}$	$I_{B1} = 0.04 \text{ A}, I_{B2} = -0.04 \text{ A}$		1.0		$\mu\text{s}$
Fall time	$t_f$	$V_{CC} = 100 \text{ V}$		0.1		$\mu\text{s}$

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. \*: Rank classification

Rank	Q	P
$h_{FE}$	60 to 140	120 to 240





Maintenance/Discontinued includes following four Product lifecycle stage.  
planned maintenance type  
maintenance type  
planned discontinued type  
discontinued type  
Please visit following URL about latest information.  
<http://www.semicon.panasonic.co.jp/en/>

### Request for your special attention and precautions in using the technical information and semiconductors described in this book

- (1) If any of the products or technical information described in this book is to be exported or provided to non-residents, the laws and regulations of the exporting country, especially, those with regard to security export control, must be observed.
- (2) The technical information described in this book is intended only to show the main characteristics and application circuit examples of the products, and no license is granted under any intellectual property right or other right owned by our company or any other company. Therefore, no responsibility is assumed by our company as to the infringement upon any such right owned by any other company which may arise as a result of the use of technical information described in this book.
- (3) The products described in this book are intended to be used for standard applications or general electronic equipment (such as office equipment, communications equipment, measuring instruments and household appliances).  
Consult our sales staff in advance for information on the following applications:
  - Special applications (such as for airplanes, aerospace, automobiles, traffic control equipment, combustion equipment, life support systems and safety devices) in which exceptional quality and reliability are required, or if the failure or malfunction of the products may directly jeopardize life or harm the human body.
  - Any applications other than the standard applications intended.
- (4) The products and product specifications described in this book are subject to change without notice for modification and/or improvement. At the final stage of your design, purchasing, or use of the products, therefore, ask for the most up-to-date Product Standards in advance to make sure that the latest specifications satisfy your requirements.
- (5) When designing your equipment, comply with the range of absolute maximum rating and the guaranteed operating conditions (operating power supply voltage and operating environment etc.). Especially, please be careful not to exceed the range of absolute maximum rating on the transient state, such as power-on, power-off and mode-switching. Otherwise, we will not be liable for any defect which may arise later in your equipment.
  - Even when the products are used within the guaranteed values, take into the consideration of incidence of break down and failure mode, possible to occur to semiconductor products. Measures on the systems such as redundant design, arresting the spread of fire or preventing glitch are recommended in order to prevent physical injury, fire, social damages, for example, by using the products.
- (6) Comply with the instructions for use in order to prevent breakdown and characteristics change due to external factors (ESD, EOS, thermal stress and mechanical stress) at the time of handling, mounting or at customer's process. When using products for which damp-proof packing is required, satisfy the conditions, such as shelf life and the elapsed time since first opening the packages.
- (7) This book may be not reprinted or reproduced whether wholly or partially, without the prior written permission of Matsushita Electric Industrial Co., Ltd.

## OUR CERTIFICATE

DiGi provide top-quality products and perfect service for customer worldwide through standardization, technological innovation and continuous improvement. DiGi through third-party certification, we stricly control the quality of products and services. Welcome your RFQ to

Email: [Info@DiGi-Electronics.com](mailto:Info@DiGi-Electronics.com)



Tel: +00 852-30501935

RFQ Email: [Info@DiGi-Electronics.com](mailto:Info@DiGi-Electronics.com)

DiGi is a global authorized distributor of electronic components.